





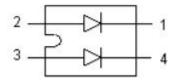
SK2S200-150 Power Schottky Rectifier



Features

- International standard package SOT-227
- Epoxy meets UL 94V-0
- Extremely low switching losses
- Low I_{RM} -values
- Copper internally DBC isolated
- UL approved file E517293
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Rectifiers in switch mode power Supplies(SMPS)
- Free wheeling diode in low voltage Converters

Advantages

- High reliability circuit operation
- Low voltage peaks for reduced Protection circuits
- Low noise switching
- Low losses

Maximum Ratings(limiting values, T_C =25°C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage	V _{RRM} V _{RWM}	-	150	V	
DC Blocking Voltage	V _{RWM} V _R		130	V	
Average Rectified Forward Current	1	50% duty cycle @T _C =110°C,	100(Per Leg)	А	
	I _{F(AV)}	rectangular wave form	200(Per Device)	A	
Peak One Cycle Non-Repetitive Surge Current (Per Leg)	I _{FSM}	8.3 ms, half Sine pulse	1400	Α	

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Electrical Characteristics:

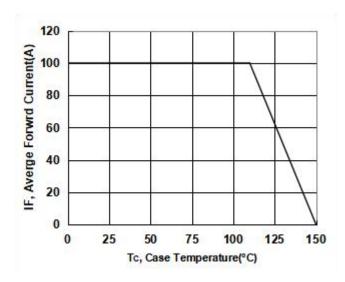
Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V _{F1}	@ 100A, Pulse, T _J = 25 °C @ 200A, Pulse, T _J = 25 °C	0.89	0.91 1.09	V
	V _{F2}	@ 100A, Pulse, T _J = 125 °C @ 200A, Pulse, T _J = 125 °C	0.82	0.85 0.99	V
Reverse Current(Per Leg)*	I _{R1}	@V _R = rated V _R , T _J = 25 °C	0.001	4	mA
	I _{R2}	@V _R = rated V _R , T _J = 125 °C	0.2	10	mA
Isolation Breakdown Voltage(R.M.S)	Visol	Ac.50H _Z ; R.M.S;1min, T _J = 25 °C	-	2500	V
	VISOI	Ac.50H _Z ; R.M.S;1sec, T _J = 25 °C	-	3500	V

^{*} Pulse width < 300 µs, duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Thermal Resistance Junction to Case(Peg Device)	R _θ JC	DC operation	0.4	°C/W
Mounting torque(M4)	M _D		1.1-1.5/9-13	Nm/
Terminal connection torque(M4)	IVID	-	1.1-1.5/9-13	lb.in.
Typical Approximate Weight	wt	-	30	g

Ratings and Characteristics Curves



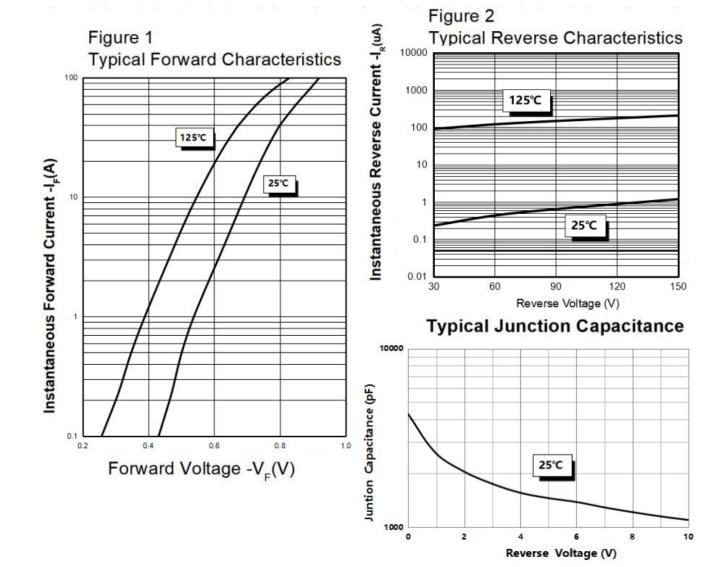
Forward Current VS Case temperature Diode

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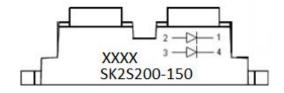




Ordering Information

Device	Package	Shipping
SK2S200-150	SOT-227 (Pb-Free)	36pcs /BULK

Marking Diagram



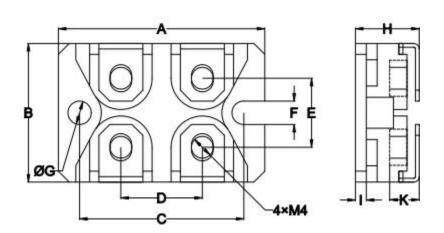
Where XXXX is YYWW

S = SMC's Power Module
K = SOT-227 Package
2 = Circuit Configuration
S = Schottky Rectifier
200 = Forward Current (200A)
150 = Reverse Voltage (150V)
YY = Year

YY = Year WW = Week

Remark: marking is as above from data code 2036.

Mechanical Dimensions SOT-227(Millimeters)



SYMBOL	Dimensions in millimeters		
	Min.	Max.	
Α	37.8	38.2	
В	24.8	25.21	
С	29.9	30.55	
D	14.5	15.5	
E	12.2	13.45	
F	4.1	4.31	
G	φ4.1	φ4.31	
Н	11	12.5	
I	1.9	2.1	
K	4.3	6.5	

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